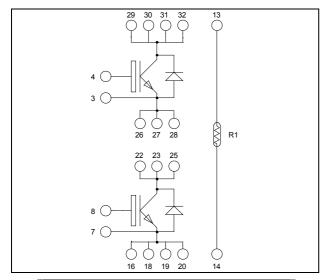


Phase leg NPT IGBT Power Module Power Module





Pins 29/30/31/32 must be shorted together
Pins 26/27/28/22/23/25 must be shorted together
to achieve a phase leg
Pins 16/18/19/20 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
- Kelvin emitter for easy drive
- Internal thermistor for temperature monitoring
- High level of integration
- AlN substrate for improved thermal performance

Benefits

- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25^{\circ}C$	210	
$I_{\rm C}$	Continuous Conector Current	$T_C = 100$ °C	150	Α
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	300	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1041	W
RBSOA	Reverse Bias Safe Operating Area	$T_{J} = 150^{\circ}C$	300A @ 1150V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
		$I_C = 150A$ $T_j = 125^{\circ}C$		3.9		·	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 6mA$		4.5	5.5	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			9.3		
Coes	Output Capacitance				1.4		nF
Cres	Reverse Transfer Capacitance				0.7		
Q_{G}	Gate charge	$V_{GE} = \pm 15V ; V_{CE} = 600V$ $I_{C} = 150A$			1.6		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ching (25°C)		120		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			50		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 150A$			310		
T_{f}	Fall Time	$R_G = 5.6\Omega$			20		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C)			130		ns
T _r	Rise Time		$V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 150A$ $R_{G} = 5.6\Omega$		60		
$T_{d(off)}$	Turn-off Delay Time				360		
T_{f}	Fall Time	$R_G = 5.6\Omega$			30		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		18		Т
E_{off}	Turn-off Switching Energy	$I_C = 150A$ $R_G = 5.6\Omega$	$T_j = 125$ °C		8		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; V_{Bi} $t_p \le 10 \mu s$; $T_j =$			900		A

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	$V_{\rm p} = 1200V$	$T_j = 25$ °C			150	۸
1 _{RM}			$T_j = 125$ °C			600	μA
I_F	DC Forward Current		Tc = 100°C		120		A
	Diode Forward Voltage	$I_{\rm F} = 120A$			2.5	3	
$V_{\rm F}$		$I_F = 240A$			3		V
		$I_{\rm F} = 120A$	$T_j = 125$ °C		1.8		
t _{rr} Reverse Recovery Time	Reverse Recovery Time		$T_j = 25$ °C		265		ns
	Reverse receivery Time	$I_F = 120A$ $V_R = 800V$	$T_{j} = 125^{\circ}C$		350		113
Q_{rr}	Reverse Recovery Charge	$di/dt = 400 A/\mu s \qquad T_j = 2$	$T_j = 25$ °C		1120		пC
			$T_{i} = 125^{\circ}C$		5780		iiC



Thermal and package characteristics

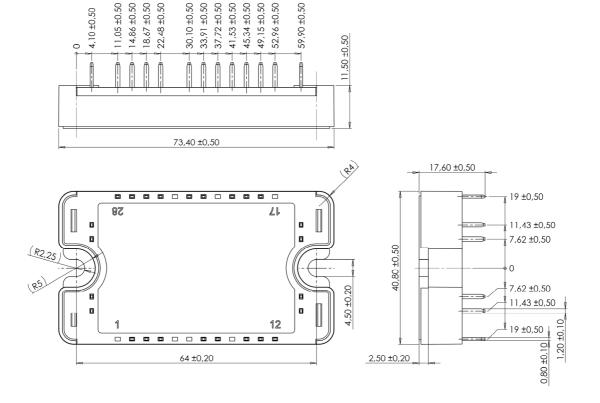
Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.12	°C/W
KthJC			Diode			0.37	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature} \\ R_{T}: \text{ Thermistor value at T}$$

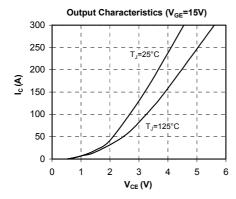
SP3 Package outline (dimensions in mm)

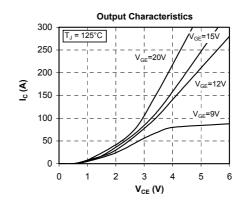


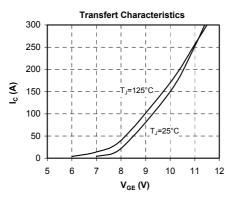
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

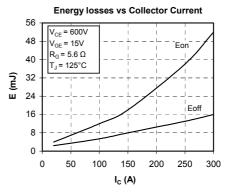


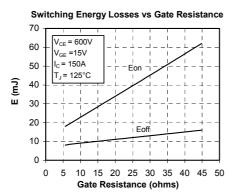
Typical Performance Curve

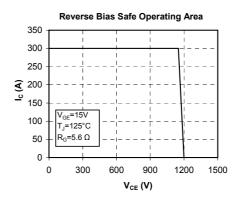


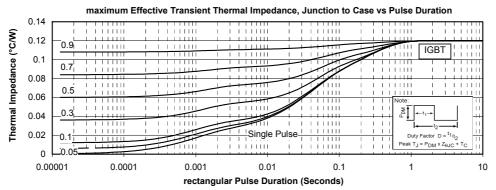






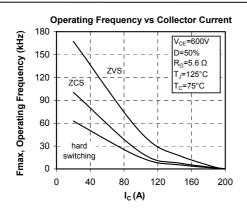


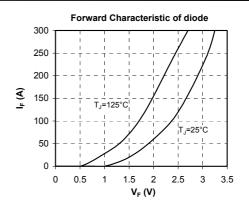


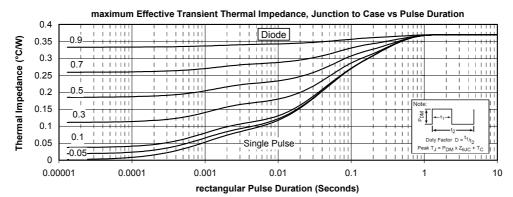


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